# NSN 5962-01-319-8466

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#### **Overall Length:**

1.290 inches

**Overall Height:** 

0.425 inches

## Overall Width:

0.620 inches

## Body Length:

1.290 inches

#### Body Width:

0.610 inches

#### **Body Height:**

0.210 inches

## Maximum Power Dissipation Rating:

1.02 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## End Application:

6111-01-212-1076

## Features Provided:

Bipolar and burn in and electrostatic sensitive and monolithic and schottky and programmed

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Complementary-metal oxide-semiconductor logic

## Input Circuit Pattern:

13 input

## Case Outline Source And Designator:

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Memory Device Type:

Rom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

2 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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